

MUN2211T1 Series

Preferred Devices

Bias Resistor Transistors

NPN Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SC-59 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Moisture Sensitivity Level: 1
- ESD Rating – Human Body Model: Class 1
– Machine Model: Class B
- The SC-59 package can be soldered using wave or reflow. The modified gull-winged leads absorb thermal stress during soldering eliminating the possibility of damage to the die.
- Available in 8 mm embossed tape and reel
Use the Device Number to order the 7 inch/3000 unit reel.
- Pb-Free Packages are Available

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	Vdc
Collector-Emitter Voltage	V_{CEO}	50	Vdc
Collector Current	I_C	100	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	230 (Note 1) 338 (Note 2) 1.8 (Note 1) 2.7 (Note 2)	mW $^\circ\text{C}/\text{W}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	540 (Note 1) 370 (Note 2)	$^\circ\text{C}/\text{W}$
Thermal Resistance – Junction-to-Lead	$R_{\theta JL}$	264 (Note 1) 287 (Note 2)	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

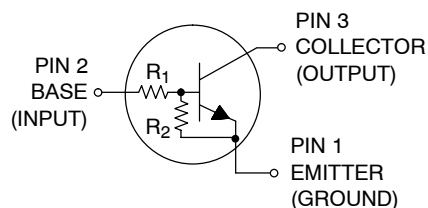
1. FR-4 @ Minimum Pad.
2. FR-4 @ 1.0 x 1.0 inch Pad.



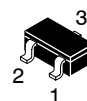
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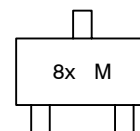
NPN SILICON BIAS RESISTOR TRANSISTORS



MARKING DIAGRAM



SC-59
CASE 318D
STYLE 1



8x = Specific Device Code*
M = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

DEVICE MARKING INFORMATION

*See specific marking information in the device marking table on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MUN2211T1 Series

DEVICE MARKING AND RESISTOR VALUES

Device	Package	Marking	R1 (K)	R2 (K)	Shipping [†]
MUN2211T1	SC-59	8A	10	10	3000/Tape & Reel
MUN2211T1G	SC-59 (Pb-Free)	8A	10	10	3000/Tape & Reel
MUN2212T1	SC-59	8B	22	22	3000/Tape & Reel
MUN2212T1G	SC-59 (Pb-Free)	8B	22	22	3000/Tape & Reel
MUN2213T1	SC-59	8C	47	47	3000/Tape & Reel
MUN2213T1G	SC-59 (Pb-Free)	8C	47	47	3000/Tape & Reel
MUN2214T1	SC-59	8D	10	47	3000/Tape & Reel
MUN2214T1G	SC-59 (Pb-Free)	8D	10	47	3000/Tape & Reel
MUN2215T1 (Note 3)	SC-59	8E	10	∞	3000/Tape & Reel
MUN2215T1G (Note 3)	SC-59 (Pb-Free)	8E	10	∞	3000/Tape & Reel
MUN2216T1 (Note 3)	SC-59	8F	4.7	∞	3000/Tape & Reel
MUN2216T1G (Note 3)	SC-59 (Pb-Free)	8F	4.7	∞	3000/Tape & Reel
MUN2230T1 (Note 3)	SC-59	8G	1.0	1.0	3000/Tape & Reel
MUN2231T1 (Note 3)	SC-59	8H	2.2	2.2	3000/Tape & Reel
MUN2232T1 (Note 3)	SC-59	8J	4.7	4.7	3000/Tape & Reel
MUN2232T1G (Note 3)	SC-59 (Pb-Free)	8J	4.7	4.7	3000/Tape & Reel
MUN2233T1 (Note 3)	SC-59	8K	4.7	47	3000/Tape & Reel
MUN2233T1G (Note 3)	SC-59 (Pb-Free)	8K	4.7	47	3000/Tape & Reel
MUN2234T1 (Note 3)	SC-59	8L	22	47	3000/Tape & Reel
MUN2236T1	SC-59	8N	100	100	3000/Tape & Reel
MUN2237T1	SC-59	8P	47	22	3000/Tape & Reel
MUN2237T1G	SC-59 (Pb-Free)	8P	47	22	3000/Tape & Reel
MUN2240T1 (Note 3)	SC-59	8T	47	∞	3000/Tape & Reel
MUN2241T1 (Note 3)	SC-59	8U	100	∞	3000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

3. New devices. Updated curves to follow in subsequent data sheets.

MUN2211T1 Series

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS (Note 5) (Continued)					
Output Voltage (off) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.5\text{ V}$, $R_L = 1.0\text{ k}\Omega$) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.050\text{ V}$, $R_L = 1.0\text{ k}\Omega$) ($V_{CC} = 5.0\text{ V}$, $V_B = 0.25\text{ V}$, $R_L = 1.0\text{ k}\Omega$)	V_{OH}	4.9	–	–	Vdc
Input Resistor	R_1	7.0	10	13	$\text{k}\Omega$
MUN2211T1		7.0	10	13	
MUN2212T1		15.4	22	28.6	
MUN2213T1		32.9	47	61.1	
MUN2214T1		7.0	10	13	
MUN2215T1		7.0	10	13	
MUN2216T1		3.3	4.7	6.1	
MUN2230T1		0.7	1.0	1.3	
MUN2231T1		1.5	2.2	2.9	
MUN2232T1		3.3	4.7	6.1	
MUN2233T1		3.3	4.7	6.1	
MUN2234T1		15.4	22	28.6	
MUN2235T1		70	100	130	
MUN2236T1		70	100	130	
MUN2237T1		32.9	47	61.1	
MUN2240T1		32.9	47	61.1	
MUN2241T1		70	100	100	
Resistor Ratio	R_1/R_2	0.8	1.0	1.2	
MUN2211T1/MUN2212T1/MUN2213T1/ MUN2236T1 MUN2214T1		0.17	0.21	0.25	
MUN2215T1/MUN2216T1/MUN2240T1/ MUN2241T1		–	–	–	
MUN2230T1/MUN2231T1/MUN2232T1 MUN2233T1		0.8	1.0	1.2	
MUN2234T1		0.055	0.1	0.185	
MUN2237T1		0.38	0.47	0.56	
MUN2237T1		1.7	2.1	2.6	

5. Pulse Test: Pulse Width < 300 μs , Duty Cycle < 2.0%.

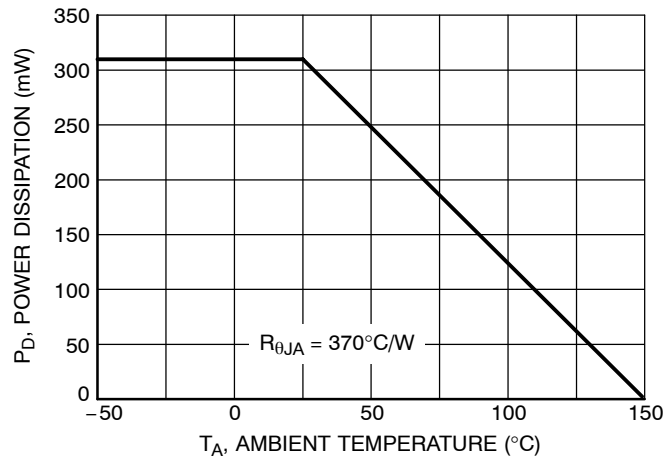


Figure 1. Derating Curve

MUN2211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2211T1

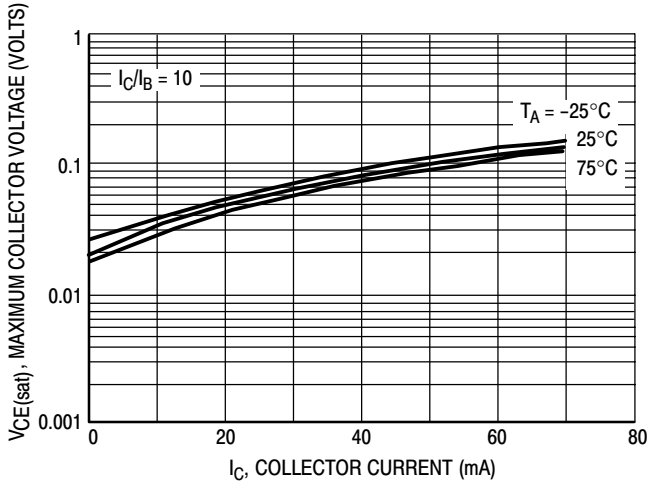


Figure 2. $V_{CE(sat)}$ versus I_C

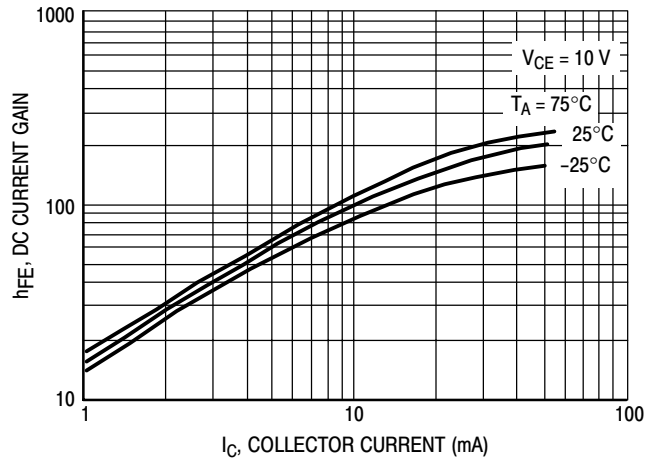


Figure 3. DC Current Gain

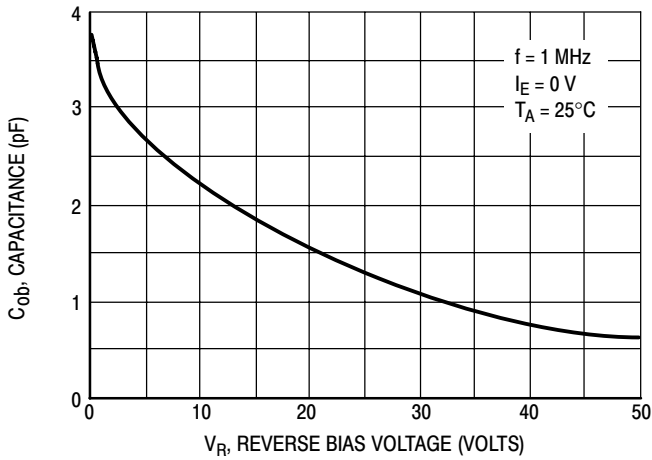


Figure 4. Output Capacitance

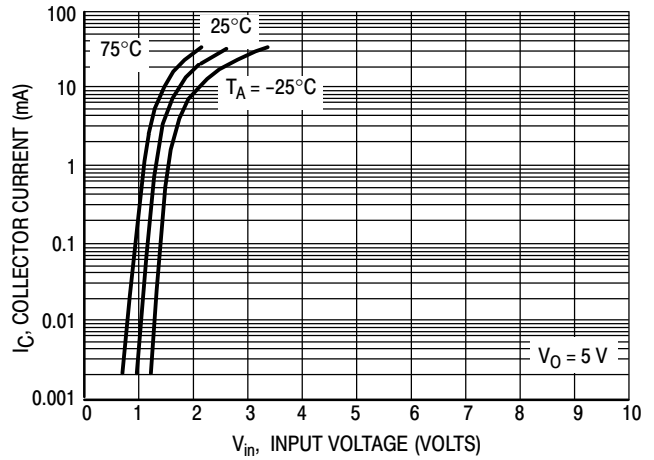


Figure 5. Output Current versus Input Voltage

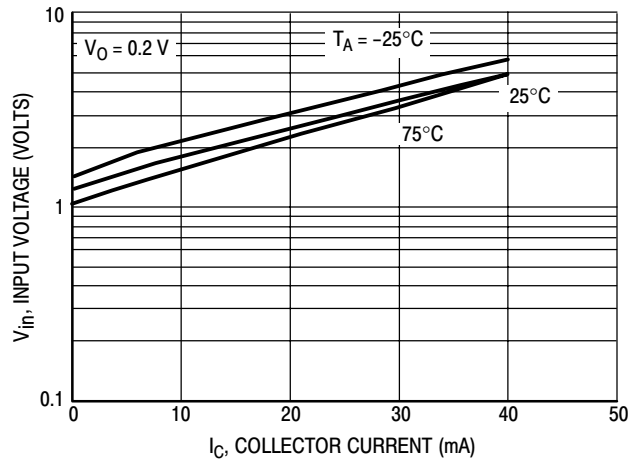


Figure 6. Input Voltage versus Output Current

MUN2211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2212T1

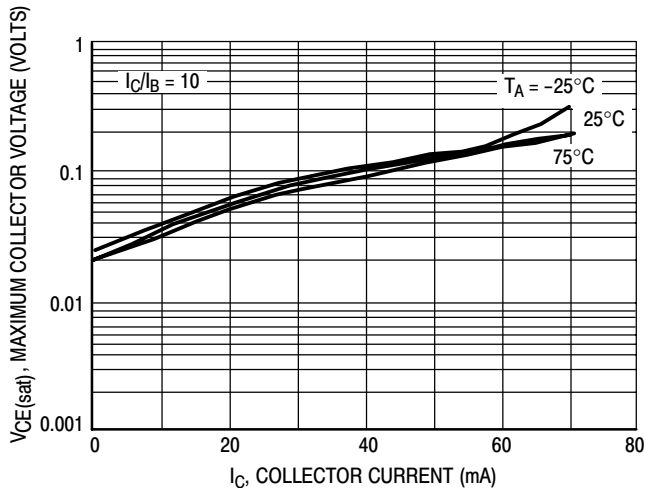


Figure 7. $V_{CE(sat)}$ versus I_C

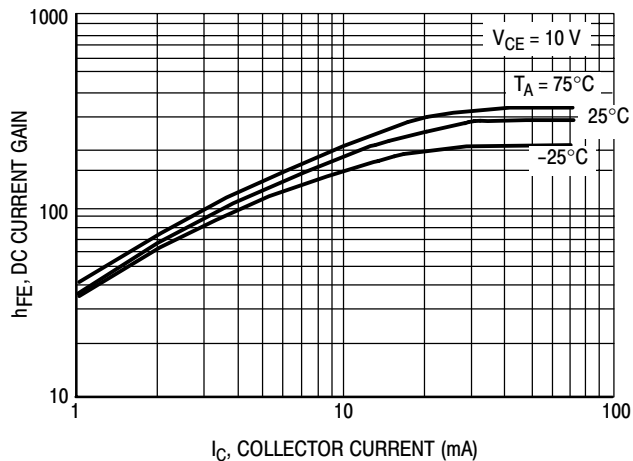


Figure 8. DC Current Gain

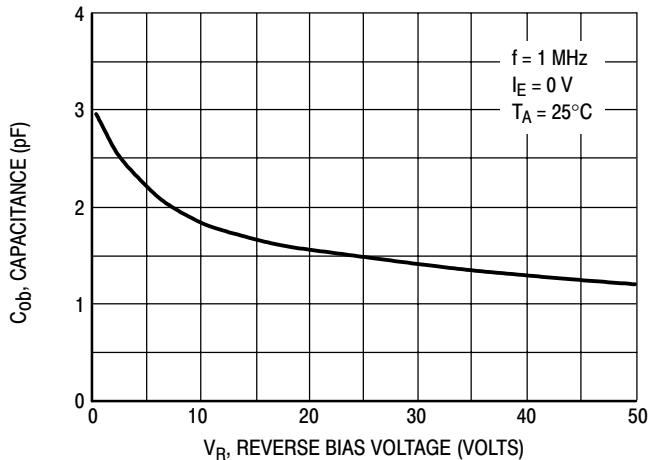


Figure 9. Output Capacitance

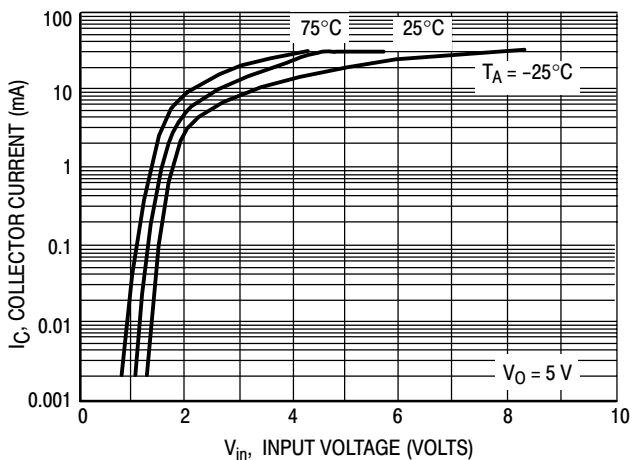


Figure 10. Output Current versus Input Voltage

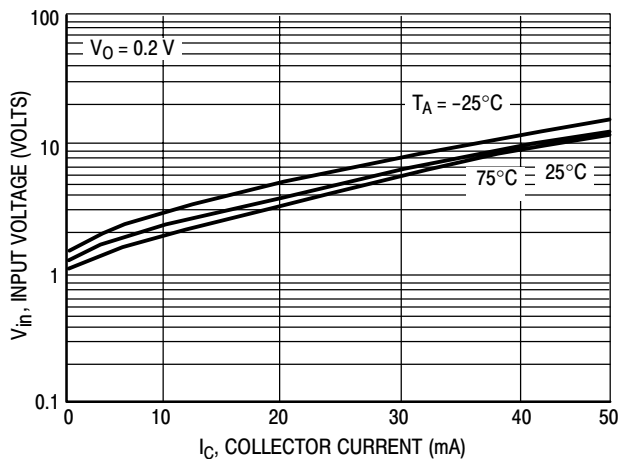


Figure 11. Input Voltage versus Output Current

MUN2211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2213T1

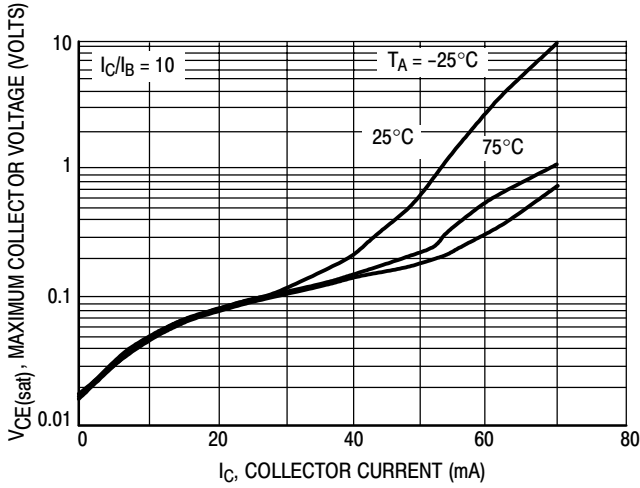


Figure 12. $V_{CE(sat)}$ versus I_C

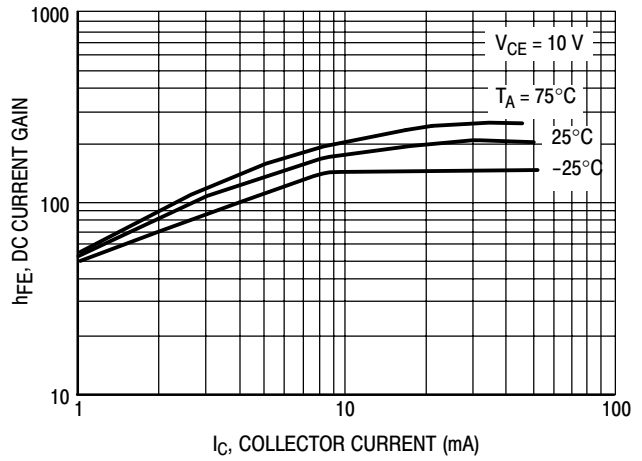


Figure 13. DC Current Gain

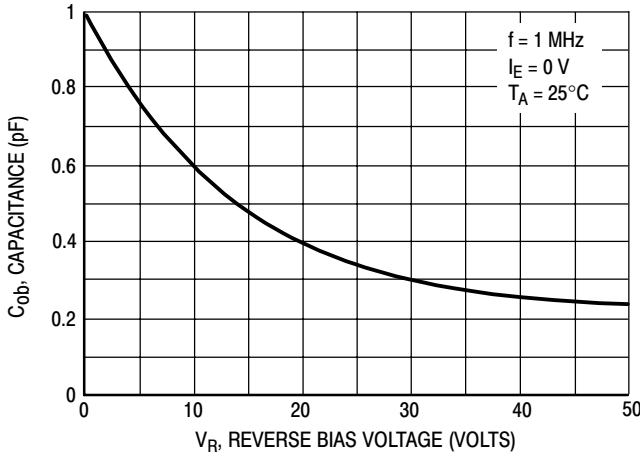


Figure 14. Output Capacitance

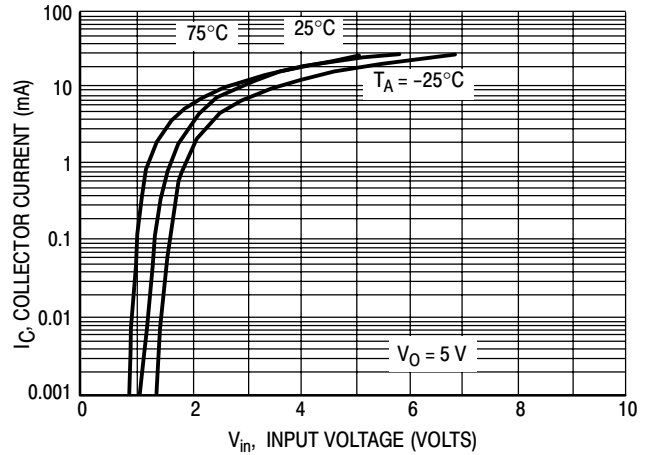


Figure 15. Output Current versus Input Voltage

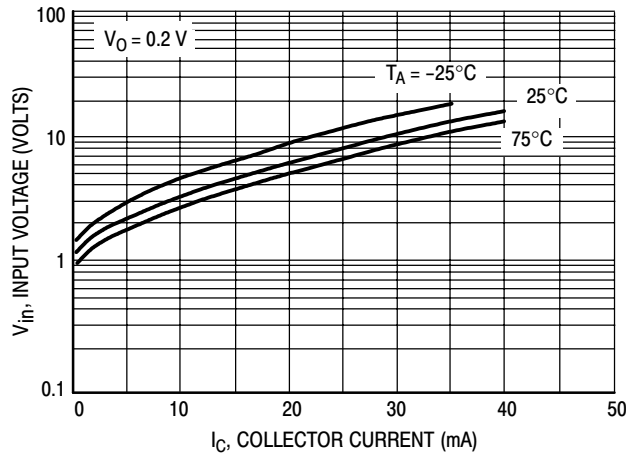


Figure 16. Input Voltage versus Output Current

MUN2211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2214T1

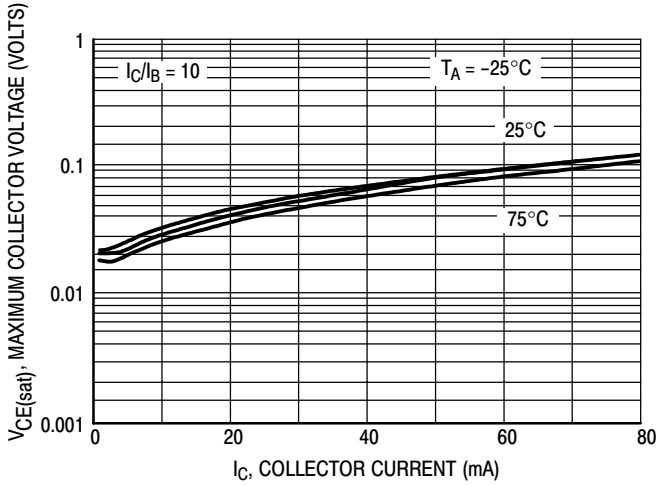


Figure 17. $V_{CE(sat)}$ versus I_C

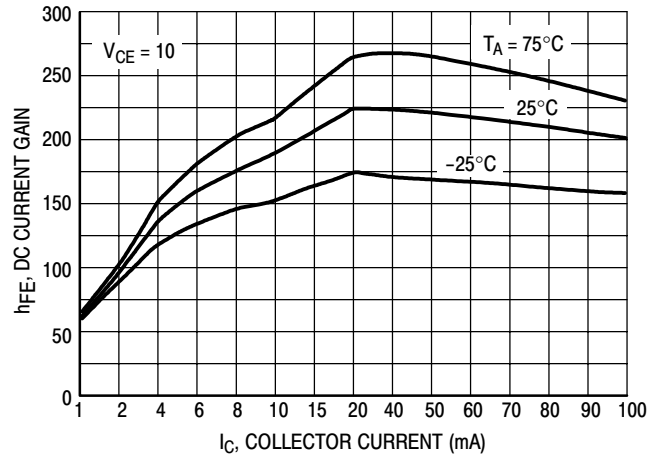


Figure 18. DC Current Gain

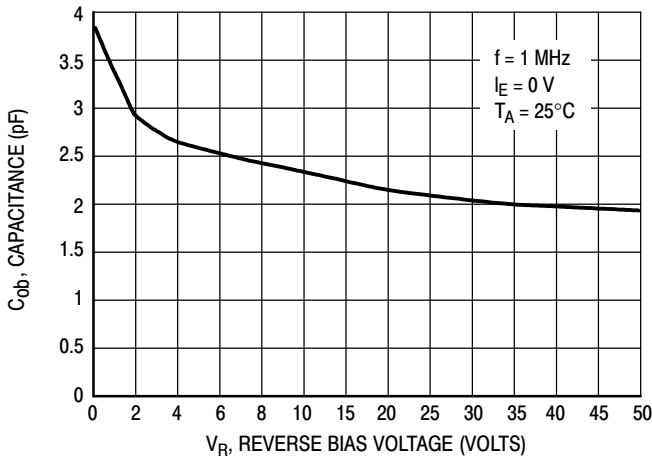


Figure 19. Output Capacitance

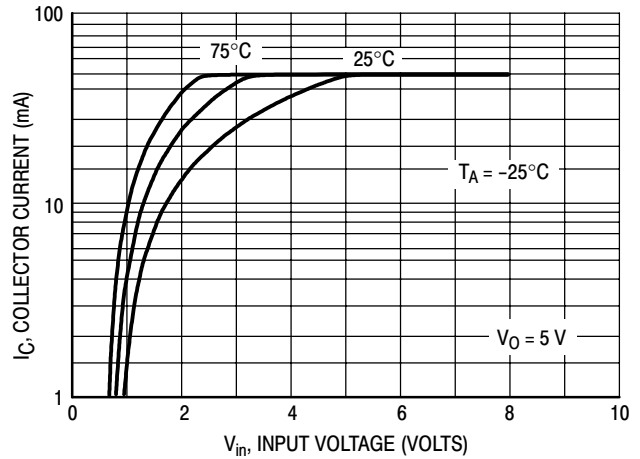


Figure 20. Output Current versus Input Voltage

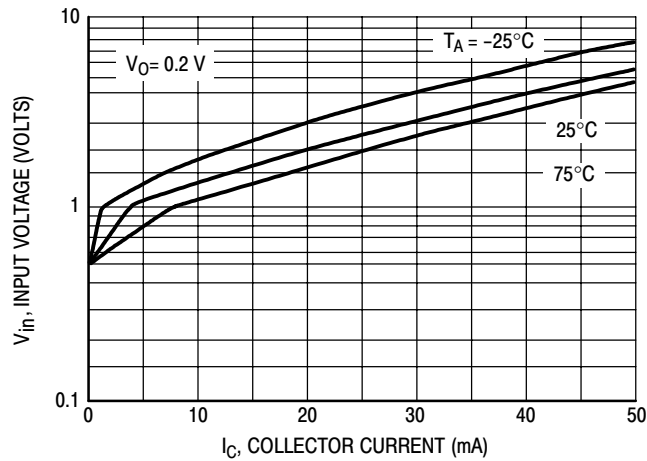


Figure 21. Input Voltage versus Output Current

MUN2211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2236T1

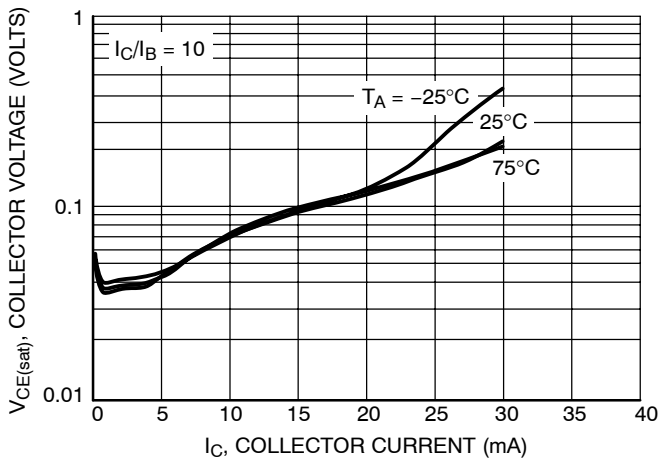


Figure 22. $V_{CE(sat)}$ versus I_C

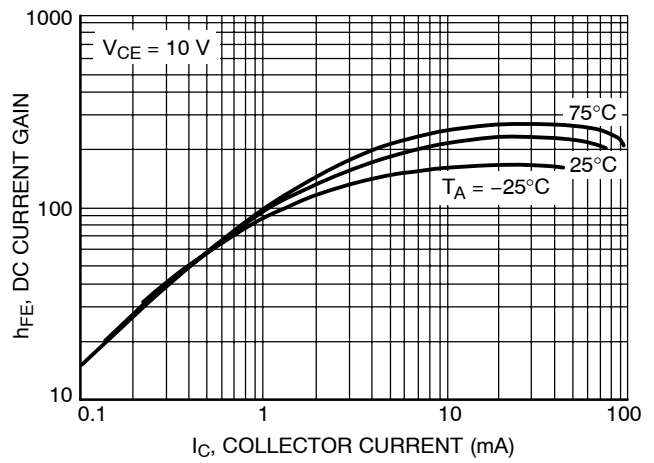


Figure 23. DC Current Gain

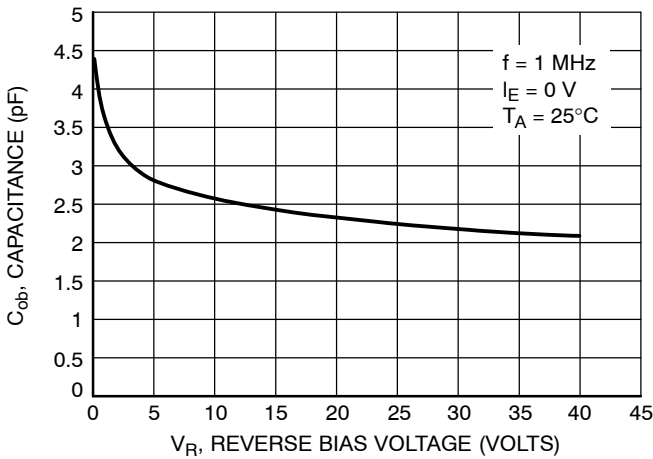


Figure 24. Output Capacitance

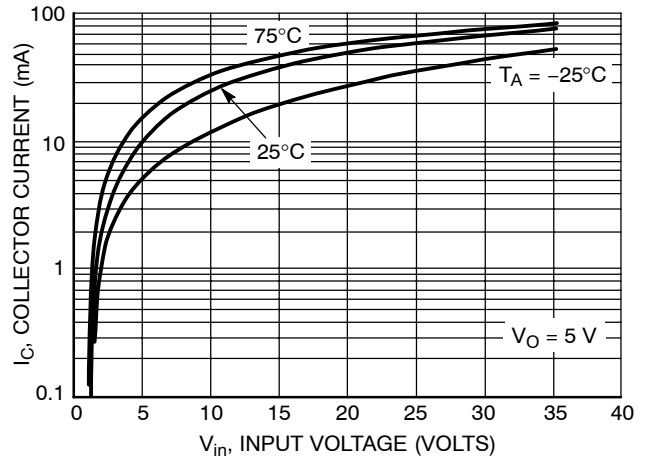


Figure 25. Output Current versus Input Voltage

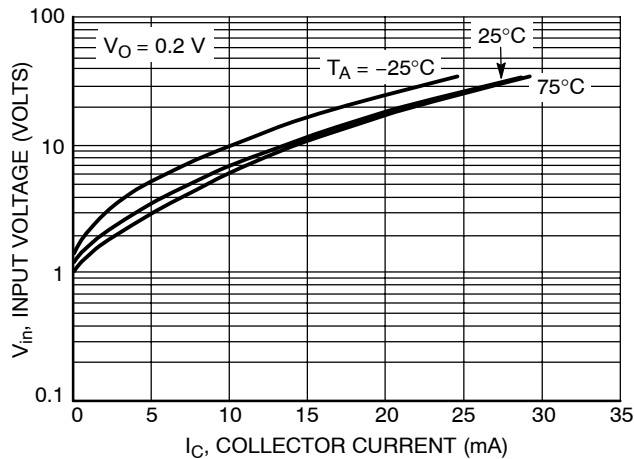


Figure 26. Input Voltage versus Output Current

MUN2211T1 Series

TYPICAL ELECTRICAL CHARACTERISTICS – MUN2237T1

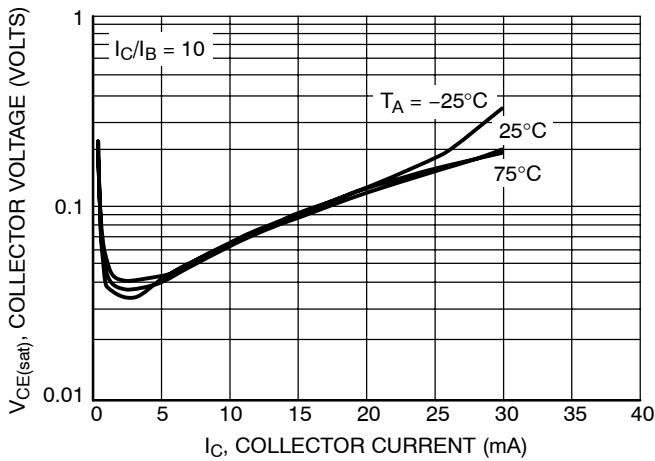


Figure 27. $V_{CE(sat)}$ versus I_C

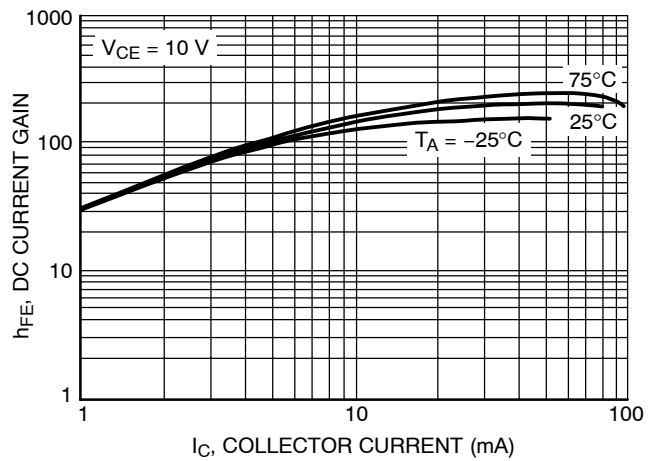


Figure 28. DC Current Gain

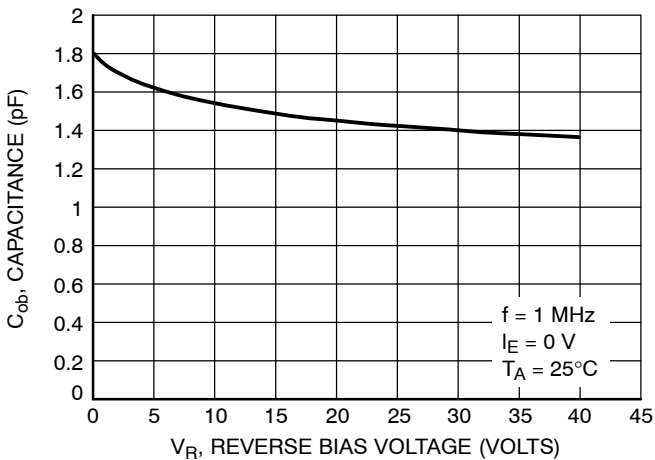


Figure 29. Output Capacitance

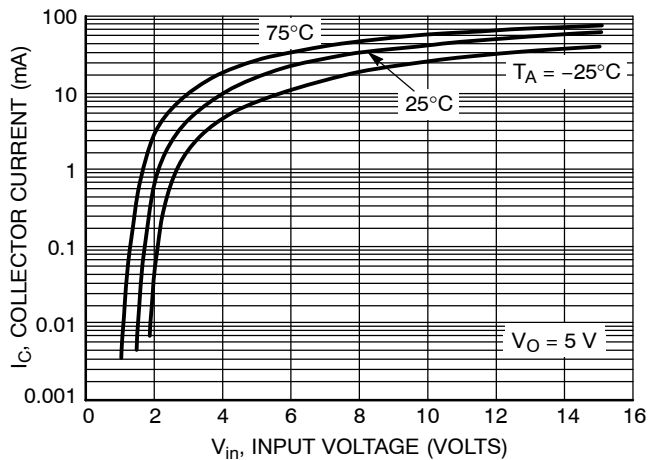


Figure 30. Output Current versus Input Voltage

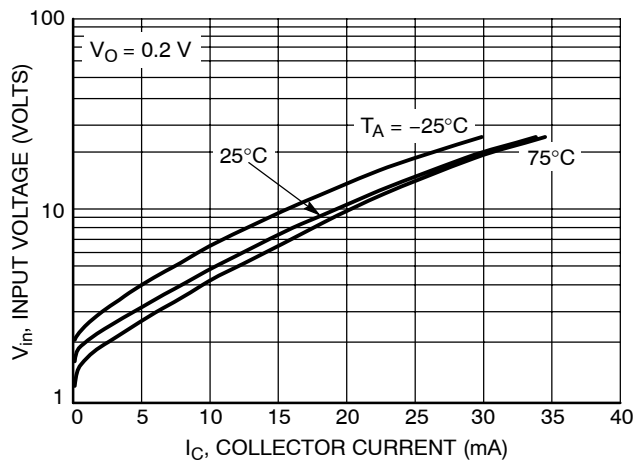


Figure 31. Input Voltage versus Output Current

MUN2211T1 Series

TYPICAL APPLICATIONS FOR NPN BRTs

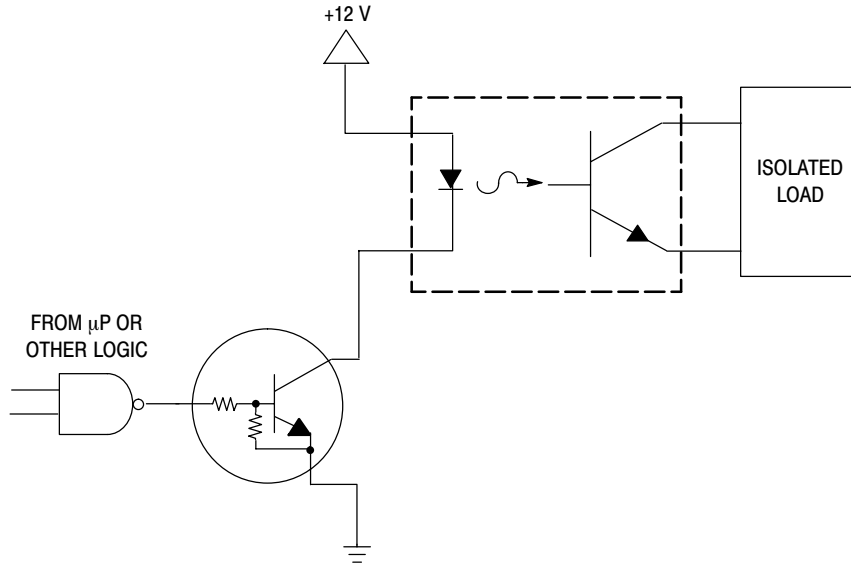


Figure 32. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

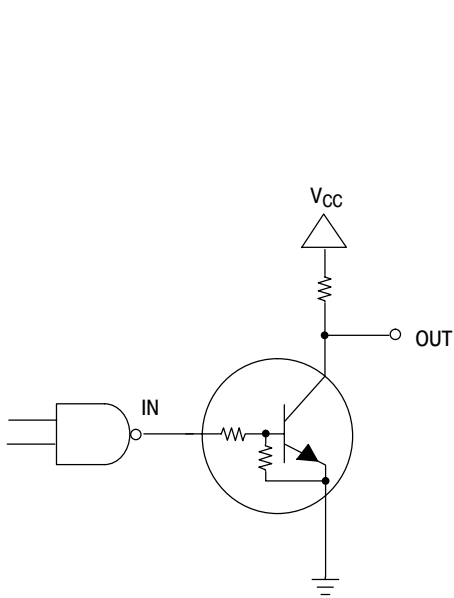


Figure 33. Open Collector Inverter:
Inverts the Input Signal

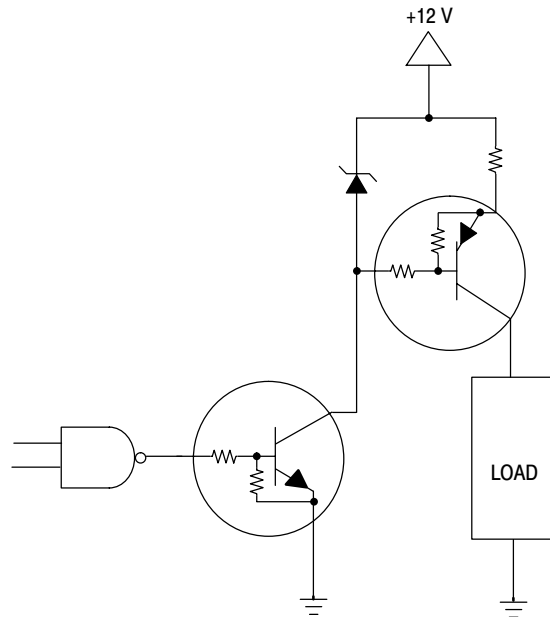
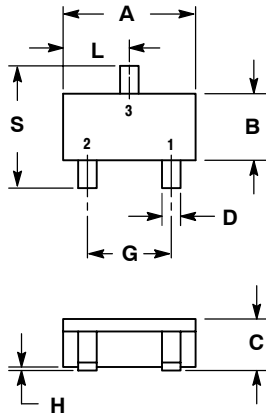


Figure 34. Inexpensive, Unregulated Current Source

MUN2211T1 Series

PACKAGE DIMENSIONS

SC-59
CASE 318D-04
ISSUE F

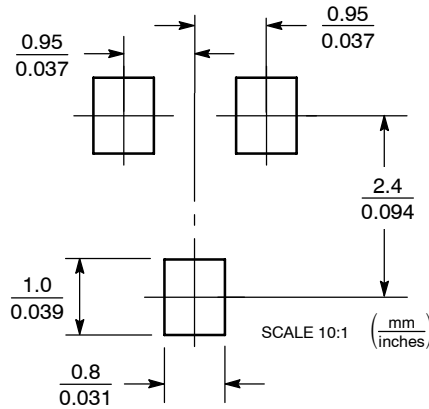


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.


DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.70	3.10	0.1063	0.1220
B	1.30	1.70	0.0512	0.0669
C	1.00	1.30	0.0394	0.0511
D	0.35	0.50	0.0138	0.0196
G	1.70	2.10	0.0670	0.0826
H	0.013	0.100	0.0005	0.0040
J	0.09	0.18	0.0034	0.0070
K	0.20	0.60	0.0079	0.0236
L	1.25	1.65	0.0493	0.0649
S	2.50	3.00	0.0985	0.1181

- STYLE 1:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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